Geometry and temperature dependent thermal conductivity of diamond nanowires: A non-equilibrium molecular dynamics study

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Abstract

Using non-equilibrium molecular dynamics methods, the analysis of geometry and temperature dependent thermal conductivities of diamond nanowires is carried out. It is found that at the same temperature conditions, thermal conductivities of diamond nanowires increase with increasing lengths, ranging from 20 to 350 nm and cross-sectional areas ranging from 2 to 30 nm². At the same length, temperature and cross-sectional area conditions, thermal conductivities of (0 1 1) crystal orientation diamond nanowires are larger than those of other crystal orientation diamond nanowires. First, in the temperature range 0–1000 K, thermal conductivities of diamond nanowires increase with the increase in temperature, and then they decrease. The results of our calculation have also indicated that all thermal conductivities of the diamond nanowires analyzed here are smaller than those of the corresponding orientations in bulk diamond. Finally, a relationship between thermal conductivity and density of phonon state is discussed.

1. Introduction

Due to their unique quantum properties and potential applications as nanocomposites for mechanical reinforcement and thermal management, diamond nanowires (DNWs) have become an important object of investigations [1–5]. Diamond nanowires were synthesized for the first time in 1997 by Shiomi [6]. After that, DNWs have been fabricated by various methods [7–12], including those based on air plasma etching of polycrystalline diamond films [7], microwave plasma assisted chemical vapor deposition [8], reactive ion etching of single crystal diamond substrates [9], hydrogen plasma etching of multiwalled carbon nanotubes [10,11] and hydrogen/argon plasma etching of Au nanodots [12].

In addition to the fabrication of DNWs, intense theoretical and experimental efforts have been focused on the mechanical and chemical properties of DNWs. For example, orientation dependent brittle fracture forces and stiffnesses have been studied using first principles calculations by Shenderova et al. [13]. Surface morphology, surface hydrogenation and diameter dependent energy band gap have also been investigated using first principles calculations by Barnard [14]. Scratching experiments have been performed to study the mechanical properties of aggregated DNWs by Dubrovinskaia et al. [15]. Electrochemical sensor experiments have been carried out by Nebel et al. [16].

In many applications of DNWs, their thermal conductive properties become a key issue. However, for nanoscale materials, it is difficult to carry out a thermal conductivity measurement experimentally. Up to date, there are no experimental reports on DNWs thermal conductivity. For theoretical calculations of properties of nanosized diamond materials, polycrystalline diamond thin films' thermal conductivity has been analyzed using the Klemens–Callaway's expression (e.g. [17]). Diamond thin films thermal conductivity has also been investigated using the molecular dynamics method by Wu et al. [18]. Carbon nanotubes and diamond nanowire thermal conductivities have been studied by atomistic simulations in the works of Moreland et al. [19,20]. Diamond nanorod's thermal conductivity has also been calculated by the molecular dynamics method by Padgett et al. [5]. Diamond nanoparticle's thermal conductivity has also been calculated by the molecular dynamics method by Li et al. [21]. However, to the best of our knowledge, geometry and temperature dependent thermal conductivity of diamond nanowires has not been studied to date in detail. To fill this gap, in this work, geometry and temperature dependent thermal conductivity of diamond nanowires will be studied using a non-equilibrium molecular dynamics method [22].

2. Computational method

By comparing the nearest neighbor separation of 1.54 Å for diamond to its de Broglie thermal wavelength, known to be 0.2899 Å at 300 K, the effectiveness of the classical molecular
dynamics method approximation has been demonstrated by a number of authors (e.g. [23]). Quantum disturbances in this case can be neglected. Therefore, DNWs thermal conductivity has been calculated using a non-equilibrium molecular dynamics method [22] and no quantum effects have been considered in this work. A schematic representation of the system we simulate is shown in Fig. 1(a). As can be seen, the cuboid represents the DNWs. To obtain temperature for different positions, DNWs were divided into n equal slabs along the z direction, and we called the first slab and the last slab as “hot” and “cold” slabs, respectively. In order to produce a simulated constant heat flux in the system, heat $\Delta E$ was added to the “hot” slab and the same heat $\Delta E$ was removed from the “cold” slab by rescaling velocities at every simulation time step. Therefore, the simulated constant heat flux can be expressed as

$$J_z = \frac{\Delta E}{\Delta tA}$$

where $\Delta t$ is the simulation time step and $A$ is cross-sectional area perpendicular to the z direction. After thermodynamic equilibrium is reached, the temperature at different positions can be obtained by computing atoms velocity $v$ at the corresponding slabs. Hence, the temperature in the mth slab $T^{m}_{\text{slab}}$ can be expressed as

$$T^{m}_{\text{slab}} = 1 \frac{Nk_B}{3Nk_B} \sum_{i=1}^{N} m_i v_i^2$$

where $N$ is the number of atoms in the slab and $k_B$ is Boltzmann’s constant. Then the temperature gradient in the z direction, $G_z$, in the position of the mth slab can be expressed as

$$G_z = \frac{n(T^{m+1}_{\text{slab}} - T^{m-1}_{\text{slab}})}{2t_{\text{slab}}}$$

where $T^{m+1}_{\text{slab}}$ and $T^{m-1}_{\text{slab}}$ are the temperatures in the positions of slabs $m+1$ and $m-1$, respectively and $l$ is the length of the DNWs. Using Fourier’s law

$$J_z = -k_z G_z$$

where $J_z$ is the heat flux in the z direction and $G_z$ the temperature gradient, and thermal conductivity in the z direction, $k_z$, can be written as

$$k_z = \frac{2l(\Delta E)}{n\Delta tA(T^{m+1}_{\text{slab}} - T^{m-1}_{\text{slab}})}$$

In this contribution, molecular dynamics (MD) calculations have been performed by employing the widely used Large-scale Atomic/Molecular Massively Parallel Simulator (LAMMPS) package [24]. In our computational scheme, C–C bonding interactions are described by the Tersoff potential [25], NPT ensemble is used and the pressure is the atmospheric pressure. Simulated input heat $\Delta E$ is 0.01 eV, and the simulation step time is 2 fs. The entire simulation time is 2 ns, which is $1 \times 10^{6}$ MD steps. Our simulation results indicated that simulation time of 2 ns is sufficient to equilibrate the nanostructure. For example, a relationship between temperature and simulation time (or time steps) for bulk diamond is shown in Fig. 1(b). This result indicates that $4 \times 10^{5}$ MD steps are sufficient to reach the steady state, and similar results hold true for all DNWs studied in this work. For different length DNWs, 15–40 slabs are required. Our simulation results have also indicated that 15–40 slabs are sufficient to obtain the temperature with necessary accuracy.

To verify the accuracy, bulk diamond thermal conductivities in the temperature range 0–1000 K have been investigated using this method. As can be seen from Fig. 2, good agreement results have been obtained when comparing our simulated values with known experimental and other theoretical results [17, 26, 27]. This indicates that our computational method and parameters are suitable for thermal conductivity calculations. We also note that similar methodologies have already been applied successfully to the analysis of several other nanostructures [28–47].
cross-sectional areas from 2.15 to 20.15 nm$^2$ and length 85.6 nm at 300 K. For the $<011>$ crystal orientation of DNWs with cross-sectional areas of 3.9 to 15.4 nm$^2$, thermal conductivities increase from 177.2 to 240.0 W K$^{-1}$ m$^{-1}$. For the $<011>$ crystal orientation of DNWs, with increasing cross-sectional areas from 2.2 to 20.2 nm$^2$, thermal conductivities increase from 264.9 to 312.1 W K$^{-1}$ m$^{-1}$. For the $<111>$ crystal orientation of DNWs, with increase in cross-sectional areas from 2.0 to 15.4 nm$^2$, thermal conductivities increase from 177.2 to 240.0 W K$^{-1}$ m$^{-1}$. For the same cross-sectional areas, thermal conductivity for the $<011>$ orientation of DNWs is larger than for the $<111>$ orientation of DNWs, and thermal conductivity for the $<111>$ orientation of DNWs is larger than for the $<001>$ orientation of DNWs. We also note that thermal conductivities of all DNWs studied here are lower than those of bulk diamond at the corresponding crystal orientation.

To understand the mechanism of cross-sectional area dependence of thermal conductivity, DNWs densities of phonon states in the $<011>$ crystal orientation have been calculated using the Fourier transform of the velocity autocorrelation function [40], and they are shown in Fig. 4. As can be seen from Fig. 4(a), with the increase in the cross-sectional area, the density of phonon state moves in the lower frequency direction. From phonon kinetic theory, the lattice thermal conductivity can be express as

$$k = (1/3)cvl$$

where $c$ is the lattice heat capacity, $v$ the mean velocity of sound and $l$ the phonon mean-free path. The phonon mean-free path depends inversely on phonon frequency [48]. This means that with decrease in phonon frequency, mean free path increases, and phonon–phonon interactions and boundary scattering are reduced, which result in an increase in thermal conductivity. As a result DNW thermal conductivities increase with an increase in the cross-sectional area.

Densities of phonon states for the $<001>$, $<011>$ and $<111>$ crystal orientations of DNWs with cross-sectional area of 10.15 nm$^2$ and length 85.6 nm are shown in Fig. 4(b). As can be seen, the prominent frequency peaks for the $<011>$, $<111>$ and $<001>$ crystal orientations of DNWs are 3.346, 4.225 and 4.771 THz, respectively. This means that the $<011>$ crystal orientation of DNW has the lowest prominent frequency and longest phonon mean-free path. At the same time, the $<001>$ crystal orientation of DNW has the highest prominent frequency and the shortest phonon mean-free path. Therefore, thermal conductivity in the $<011>$ crystal orientation is larger than in other crystal orientations.
3.2. Length dependent thermal conductivity

In order to analyze the length effect on thermal conductivity, thermal conductivities of DNWs with length range 26.7–357.1 nm have been computed at 300 K. Three crystal orientations (\langle 011 \rangle, \langle 011 \rangle and \langle 111 \rangle) of DNWs have been considered. All DNWs cross sectional areas have been 2.2 nm². The relationship between length and thermal conductivity for these three crystal orientations of DNWs are shown in Fig. 5. It can be seen that for the \langle 011 \rangle crystal orientation, thermal conductivity increases from 66.9 to 484.3 W K⁻¹ m⁻¹ with increase in length range from 26.7 to 354.6 nm. However, for the \langle 001 \rangle crystal orientation, when length increases from 26.75 to 356.68 nm, thermal conductivity increases from 61.53 to 301.92 W K⁻¹ m⁻¹. In particular, our results show that DNW thermal conductivity in the \langle 011 \rangle crystal orientation is significantly larger than in the \langle 001 \rangle and \langle 111 \rangle crystal orientations. This has also indicated that thermal conductivities in all DNWs considered here are lower than those of corresponding crystal orientations bulk diamond.

In this work, densities of phonon states for the \langle 011 \rangle crystal orientation of DNWs with different lengths from 60 to 320 nm have been calculated, and they are shown in Fig. 6. Our results show that the prominent frequency peak for all DNWs densities of phonon states have the same prominent frequency peak at 5.378 THz. With increase in DNW length, the intensity of prominent frequency peak decreases and the phonon mean-free path increases. This implies that phonon scattering and boundary scattering are reduced with increase in DNW length. Therefore, thermal conductivity increases with increase in DNW length.

3.3. Temperature dependent thermal conductivity

In this contribution, temperature dependent thermal conductivities of DNWs have been investigated in the temperature range 0–1000 K. All DNW cross-sectional areas studied here have been 2.2 nm². DNWs with three crystal orientations (\langle 011 \rangle, \langle 111 \rangle and \langle 001 \rangle) and with four different lengths (53, 125, 250 and 320 nm) have been studied. The relationships between temperature and thermal conductivity are shown in Fig. 7. It can be seen that initially thermal conductivities of all DNWs increase with increase in temperature, and then decrease. However, for different lengths and crystal orientations of DNWs, the temperature position for maximum thermal conductivity is different. For all crystal orientations of DNWs, the temperature position for maximum thermal conductivity decreases with increase in DNW’s length.

To study the mechanism of temperature dependent thermal conductivity, densities of phonon states have been calculated for the \langle 011 \rangle crystal orientation of DNWs at temperatures 100, 200, 400 and 600 K. The DNWs length is 53 nm and cross-sectional area is 2.2 nm² at 300 K. As can be seen from Fig. 8, all densities of phonon states have the same prominent frequency peak at 5.413 THz. Moreover, initially the intensities of these prominent frequency peaks decrease with increase in temperature, and then increase. This is why thermal conductivities initially increase with increase in temperature, and then decrease.

4. Conclusions

In summary, we have presented non-equilibrium molecular dynamics simulations on geometry and temperature dependent thermal conductivities of diamond nanowires. Our calculated...
results indicated that at temperature 300 K, diamond nanowire thermal conductivities increase with increase in length and cross-sectional areas. It is also found that at the same length, temperature and cross-sectional area, thermal conductivities of the $\langle 011 \rangle$ crystal orientation DNWs are larger than those in the $\langle 001 \rangle$ and $\langle 111 \rangle$ crystal orientations DNWs. All diamond nanowires thermal conductivities considered in this work are smaller than those of the corresponding orientations bulk diamond. In addition, in the temperature range 0–1000 K, diamond nanowire's thermal conductivities initially increase with increasing temperature, and then decrease. Geometry and temperature effects on diamond nanowires thermal conductivities can be explained well by calculated densities of phonon states.

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Reference


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